# ISD3800

Digital ChipCorder with

**Digital Audio Interface** 

### nuvoton

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#### 1 GENERAL DESCRIPTION

The ISD3800 is a digital ChipCorder<sup>®</sup> featuring digital compression, comprehensive memory management, and integrated analog/digital audio signal paths. The ISD3800 utilizes serial flash memory to provide non-volatile audio playback for a two-chip solution. The ISD3800 provides an I<sup>2</sup>S digital audio interface, faster digital programming, higher sampling frequency, and a signal path with SNR 80dB.

The ISD3800 can take digital audio data via I<sup>2</sup>S or SPI interface. When I<sup>2</sup>S input is selected, it will replace the analog audio inputs and will support sample rates of 32, 44.1 or 48 kHz depending upon clock configuration. When SPI interface is chosen, the sample rate of the audio data sent must be one of the ISD3800 supported sample rates.

The ISD3800 has inbuilt analog audio inputs, analog audio line driver, and speaker driver output.

The analog audio input, Aux-in, has a fixed gain configured by SPI command. Aux-in can directly feed-through to the analog outputs; it can also mix with the DAC output and then feed-through to the analog outputs.

Analog outputs are available in two forms: (1) Aux-out is an analog single-ended voltage output; (2) Class-AB BTL (bridge-tied-load) is an analog differential voltage output. Class-AB BTL delivers 1-watt output power at  $V_{CCSPK} = 5V$ .

Class-D PWM direct-drive is also available, which delivers 1-watt output power at V<sub>CCSPK</sub> = 5V.

#### **2 FEATURES**

- External Memory:
  - o The ISD3800 supports the following flash:

Manufacturer	Wint	oond		MXIC		
Family	25X	25Q	25P	25PX	25PE	25L / 25V
JEDEC ID	EF 30 1X	EF 40 1X	20 20 1X	20 71 1X	20 80 1X	C2 20 1X

- The addressing ability of ISD3800 is up to 128Mbit, which is 64-minute playback time based on 8kHz/4bit ADPCM.
- Inbuilt 3V voltage regulator to provide power source to the external flash memory
- Fast Digital Programming
  - Programming rate can go up to 1Mbits/second mainly limited by the flash memory write rate.
- Memory Management
  - Store pre-recorded audio (Voice Prompts) using high quality digital compression
  - Use a simple index-based command for playback
  - Execute pre-programmed macro scripts (Voice Macros) designed to control the configuration
    of the device and play back Voice Prompts sequences.
- Sample Rate
  - Seven sampling frequencies are available for a given master sample rate. For example, the sampling frequencies of 4, 5.3, 6.4, 8, 12.8, 16 and 32kHz are available when the device is clocked at a 32kHz master sample rate.
  - For I<sup>2</sup>S operation, 32, 44.1 and 48kHz master sample rates are available with playback sampling frequencies scaling accordingly.
- Compression Algorithms
  - For Pre-Recorded Voice Prompts
    - μ-Law: 6, 7 or 8 bits per sample

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- Differential μ-Law: 6, 7 or 8 bits per sample
- PCM: 8, 10 or 12 bits per sample
- Enhanced ADPCM: 2, 3, 4 or 5 bits per sample
- Variable-bit-rate optimized compression. This allows best possible compression given a metric of SNR and background noise levels.
- Oscillator
  - o Internal oscillator with internal reference: 2.048 MHz with ±1% deviation
  - Internal oscillator with external resistor: 2.048 MHz with ±2% deviation<sup>1</sup>
  - External crystal or clock input
    - Crystals support standard audio sampling rates of 2.048, 4.096, 8.192, 12.288 and 11.2896MHz
  - I<sup>2</sup>S bit clock input
- Inputs
  - Aux-in: Analog input with 2-bit gain control configured by SPI command
- Outputs
  - PWM: Class-D speaker driver to directly drive an 8Ω speaker or buzzer
    - Deliver 1-watt output power at V<sub>CCSPK</sub> = 5V
  - Aux-out: an analog single-ended voltage output
  - Class-AB BTL: an analog differential voltage output
    - Deliver 1-watt output power at V<sub>CCSPK</sub> = 5V
    - Class-AB BTL can directly drive an 8Ω speaker or buzzer
    - Class-AB BTL can drive an 8Ω speaker or buzzer via an external amplifier
- I/Os
  - SPI interface: MISO, MOSI, SCLK, SSB for commands and digital audio data
  - o I<sup>2</sup>S interface: I<sup>2</sup>S CLK, I<sup>2</sup>S WS, I<sup>2</sup>S SDI, I<sup>2</sup>S SDO for digital audio data
  - o 8 GPIO pins:
    - 4 GPIO pins share with I<sup>2</sup>S
    - 4 GPIO pins share with SPI Interface
    - GPIO pins can trigger Voice Macro for a pushbutton application
- 8-bit Volume Control set by SPI command for flexible mixing
- Operating Voltage: 2.7 ~ 5.5V
- Standby Current: 1uA typical
- Package:
  - Green 48L-LQFP
- Temperature Options:
  - Industrial: -40°C to 85°C

-

With ±1% precision 80kohm external resistor.



#### 3 BLOCK DIAGRAM

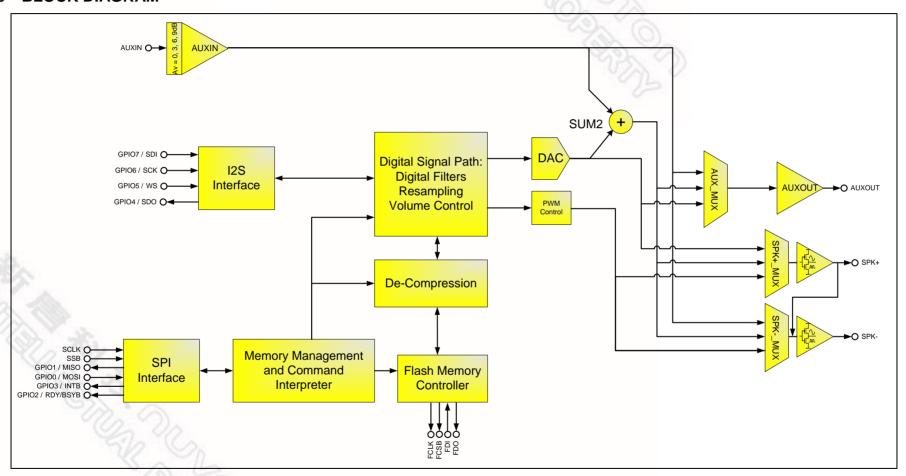


Figure 3-1 ISD3800 Block Diagram



#### **4 PINOUT CONFIGURATION**

#### 4.1 48L-LQFP

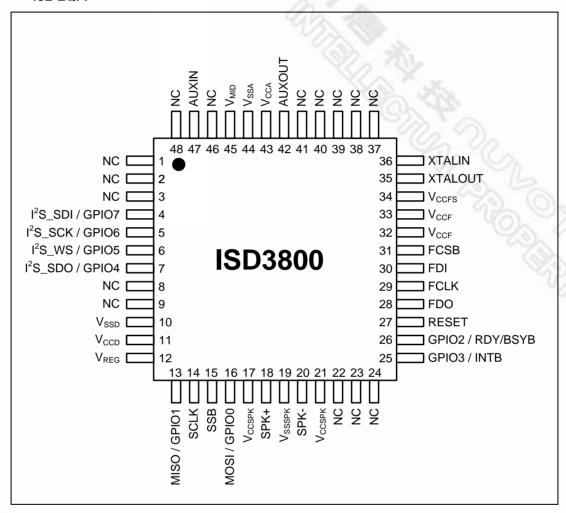


Figure 4-1 ISD3800 48-Lead LQFP Pin Configuration.



### **5 PIN DESCRIPTION**

Pin Number 48L- LQFP	Pin Name	I/O	Function
1	NC		This pin should be left unconnected.
2	NC		This pin should be left unconnected.
3	NC		This pin should be left unconnected.
4	GPIO7 / I <sup>2</sup> S_SDI	I/O	A GPIO pin. By default this pin is a pull-high input.  Can be configured as Serial Data Input of the I <sup>2</sup> S interface.
5	GPIO6 / I <sup>2</sup> S_SCK	I/O	A GPIO pin. By default this pin is a pull-high input.  Can be configured as Clock input in slave mode or clock output in master mode. This pin can be configured as an external clock buffer if I <sup>2</sup> S is not used.
6	GPIO5 / I <sup>2</sup> S_WS	I/O	A GPIO pin. By default this pin is a pull-high input. Can be configured as Word Select (WS) input in slave mode or WS output in master mode.
7	GPIO4 / I <sup>2</sup> S_SDO	I/O	A GPIO pin. By default this pin is a pull-high input. Can be configured as Serial Data Output of the I <sup>2</sup> S Interface.
8	NC		This pin should be left unconnected.
9	NC		This pin should be left unconnected.
10	$V_{SSD}$	I	Digital Ground.
11	V <sub>CCD</sub>	I	Digital power supply.
12	$V_{REG}$	0	A 1.8V regulator to supply the internal logic. A minimum 1uF capacitor with low ESR<0.5OHM should be connected to this pin for supply decoupling and stability.
13	MISO / GPIO1	0	Master-In-Slave-Out. Serial output from the ISD3800 to the host. This pin is in tri-state when SSB=1. Can be configured as GPIO1.
14	SCLK	I	Serial Clock input to the ISD3800 from the host.
15	SSB	I	Slave Select input to the ISD3800 from the host. When SSB is low device is selected and responds to commands on the SPI interface.
16	MOSI / GPIO0	3	Master-Out-Slave-In. Serial input to the ISD3800 from the host. Can be configured as GPIO0.



Pin Number 48L- LQFP	Pin Name	I/O	Function
17	V <sub>CCSPK</sub>	_	In PWM mode: Digital Power for the PWM Driver. Deliver 1-watt output power at $V_{CCSPK} = 5V$ . Or, In Class-AB mode: Analog Power for the Class-AB output. Class-AB BTL delivers 1-watt output power at $V_{CCSPK} = 5V$ .
18	SPK+	0	PWM driver positive output. This SPK+ output, together with SPK-pin, provide a differential output to drive 8Ω speaker or buzzer. During power down this pin is in tri-state.  Or, can be configured as Class-AB BTL which, together with SPK-pin, provides a differential voltage output.  Or, can be configured as a Class-AB single-ended output.
19	V <sub>SSSPK</sub>	I	In PWM mode: Digital Ground for the PWM Driver. Or, In Class-AB mode: Analog Ground for the Class-AB output.
20	SPK-	0	PWM driver negative output. This SPK- output, together with SPK+ pin, provides a differential output to drive 8Ω speaker or buzzer. During power down this pin is tri-state.  Or, can be configured as Class-AB BTL which, together with SPK+ pin, provides a differential voltage output.  Or, can be configured as a Class-AB single-ended output.
21	V <sub>CCSPK</sub>	I	In PWM mode: Digital Power for the PWM Driver. Deliver 1-watt output power at $V_{CCSPK} = 5V$ . Or, In Class-AB mode: Analog Power for the Class-AB output. Class-AB BTL delivers 1-watt output power at $V_{CCSPK} = 5V$ .
22	NC		This pin should be left unconnected.
23	NC		This pin should be left unconnected.
24	NC		This pin should be left unconnected.
25	INTB / GPIO3	0	Active low interrupt request pin. This pin is an open-drain output. Can be configured as GPIO3.
26	RDY/BSYB / GPIO2	0	An output pin to report the status of data transfer on the SPI interface. "High" indicates that ISD3800 is ready to accept new SPI commands or data.  Can be configured as GPIO2.
27	RESET	50	Applying power to this pin will reset the chip. (A high pulse of 50ms or more will reset the chip.)



Pin Number 48L- LQFP	Pin Name	I/O	Function
28	FDO	0	Serial data output of the external serial flash interface. Connects to data input (DI) of external serial flash.
29	FCLK	0	Serial data CLK of the external serial flash interface.
30	FDI		Serial data input to external serial flash interface. Connects to data output (DO) of external flash memory.
31	FCSB	0	Chip Select Bar of the external serial flash interface.
32	V <sub>CCF</sub>	0	Digital power supply for the external flash memory. A minimum 1uF capacitor with low ESR<0.5OHM should be connected to this pin for supply decoupling and stability. Refer to the application diagram.
33	V <sub>CCF</sub>	0	Digital power supply for the external flash memory. A minimum 1uF capacitor with low ESR<0.5OHM should be connected to this pin for supply decoupling and stability. Refer to the application diagram.
34	V <sub>CCFS</sub>	I	Digital power supply for the inbuilt voltage regulator for the external flash memory. A 0.1uF capacitor should be connected to this pin for supply decoupling and stability. Refer to the application diagram.
35	XTALOUT	0	Crystal interface output pin.
36	XTALIN	ı	The CLK_CFG register determines one of the following three configurations: (1) A crystal or resonator connected between the XTALOUT and XTALIN pins. (2) A resistor connected to GND as a reference current to the internal oscillator and left the XTALOUT unconnected. (3) An external clock input to the device and left the XTALOUT unconnected.
37	NC		This pin should be left unconnected.
38	NC		This pin should be left unconnected.
39	NC		This pin should be left unconnected.
40	NC		This pin should be left unconnected.
41	NC		This pin should be left unconnected.
42	Aux-out	0	Aux Out. This pin is an analog voltage output.  If AUXOUT is not used, this pin should be left unconnected.
43	V <sub>CCA</sub>	I	Analog power supply pin.
44	V <sub>SSA</sub>	I	Analog ground pin.
45	V <sub>MID</sub>	0	Middle voltage reference for the swing of analog/digital audio outputs. A 4.7uF capacitor should be connected to this pin for supply decoupling and stability.
46	NC	16	This pin should be left unconnected.



Pin Number 48L- LQFP	Pin Name	I/O	Function
47	Aux-in	I	Auxiliary input with the gain set by SPI command If Aux-in is not used, this pin should be left unconnected.
48	NC		This pin should be left unconnected.



#### **6 ELECTRICAL CHARACTERISTICS**

#### 6.1 OPERATING CONDITIONS

### **OPERATING CONDITIONS (INDUSTRIAL PACKAGED PARTS)**

CONDITIONS	VALUES
Operating temperature range (Case temperature)	-40°C to +85°C
Digital Supply voltage (V <sub>CCD</sub> ) [1]	+2.7V to +5.5V
Digital Ground voltage (V <sub>SSD</sub> ) [2]	0V
Analog Supply voltage (V <sub>CCA</sub> ) [3]	+2.7V to +5.5V
Analog Ground voltage (V <sub>SSA</sub> ) [2]	0V
Speaker Supply voltage (V <sub>CCSPK</sub> ) [3]	+2.7V to +5.5V
Speaker Ground voltage (V <sub>SSSPK</sub> ) [2]	0V
Flash Source Supply voltage (V <sub>CCFS</sub> ) [4] – to regulate V <sub>CCF</sub>	+2.7V to +5.5V
Flash Source Supply voltage $(V_{CCFS})^{[4]}$ – tied to $V_{CCF}$	+2.25V to +3.6V
Flash Supply voltage - (V <sub>CCF</sub> ) [4] – regulated from V <sub>CCFS</sub>	+2.4V to +3.0V
Flash Supply voltage - (V <sub>CCF</sub> ) [4] - tied to V <sub>CCFS</sub>	+2.25V to +3.6V

#### NOTES:

 $<sup>^{[4]}</sup>$  If  $V_{CCFS}$  is guaranteed to be below 3.6V (or upper flash supply limit), then  $V_{CCF}$  should be tied to  $V_{CCFS}$ .

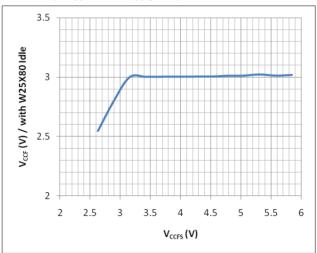


Figure 6-1  $V_{\text{CCF}}$  vs.  $V_{\text{CCFS}} - V_{\text{CCF}}$  is regulated internally from  $V_{\text{CCFS}}^{[4]}$ 

 $<sup>^{[1]}</sup>V_{\text{CCD}}$  2.7 ~ 5.5V; No restrictions with respect to  $V_{\text{CCA}}$  and  $V_{\text{CCSPK}}.$ 

 $<sup>^{[2]}</sup>V_{SSD} = V_{SSA} = V_{SSSPK}$ 

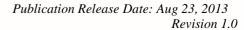
<sup>&</sup>lt;sup>[3]</sup> In Class-AB mode:  $V_{CCSPK}$  must equal  $V_{CCA}$ . Otherwise:  $V_{CCSPK} \ge V_{CCA}$ .



#### 6.2 DC PARAMETERS

PARAMETER	SYMBOL	MIN	TYP [1]	MAX	UNIT S	CONDITIONS
Digital Supply Voltage	$V_{CCD}$	2.7	93	5.5	V	
Analog Supply Voltage	$V_{CCA}$	2.7		5.5	V	
Speaker Supply Voltage	V <sub>CCSPK</sub>	2.7		5.5	V	
Flash Source Supply	\/	2.7		5.5	V	to regulate V <sub>CCF</sub>
Voltage	V <sub>CCFS</sub>	2.25		3.6	V	tied to V <sub>CCF</sub>
Flash Supply Voltage (refer to Figure 6-1)			V <sub>CCFS</sub>		(8)	regulated from $V_{CCFS}$ $V_{CCFS} = 2.7 \sim 3.3V$
	V <sub>CCF</sub>		3.0		V	regulated from $V_{CCFS}$ $V_{CCFS} = 3.3 \sim 5.5V$
		2.25		3.6		tied to V <sub>CCFS</sub>
Input Low Voltage	V <sub>IL</sub>	V <sub>SSD</sub> -0.3		0.3xV <sub>CCD</sub>	V	200
Input High Voltage	V <sub>IH</sub>	0.7xV <sub>CCD</sub>		V <sub>CCD</sub>	V	6.9 5
Output Low Voltage	V <sub>OL</sub>	V <sub>SSD</sub> -0.3		0.3xV <sub>CCD</sub>	V	I <sub>OL</sub> = 1mA
Output High Voltage	V <sub>OH</sub>	0.7xV <sub>CCD</sub>		V <sub>CCD</sub>	V	I <sub>OH</sub> = -1mA
INTB Output Low Voltage	V <sub>OH1</sub>			0.4	V	
Playback Current	I <sub>DD_Playback</sub>			30	mA	
Standby Current	I <sub>SB</sub>		1	10	μA	
Input Leakage Current	I <sub>IL</sub>		±1		μA	Force V <sub>CCD</sub>

Notes: [1] Conditions V<sub>CCD</sub>=V<sub>CCA</sub>=V<sub>CCSPK</sub>=V<sub>CCFS</sub>=3V, T<sub>A</sub>=25°C unless otherwise stated





#### 6.3 AC PARAMETERS

#### 6.3.1 Internal Oscillator

Parameter	Symbol	Min	Тур	Max	Units	CONDITIONS
Internal oscillator with internal reference	FINT	-1%	2.048 MHz	+1%	MHz	V <sub>CCD</sub> = 3.3V. At room temperature.
Internal oscillator with external reference	F <sub>ЕХТ</sub>	-2%	2.048 MHz	+2%	MHz	With ±1% precision resistor, 80kohm. V <sub>CCD</sub> = 3.3V. At room temperature.

### **6.3.2** Inputs

#### **AUX-IN:**

Conditions:  $V_{CCD} = 3.3V$ ,  $V_{CCA} = V_{CCSPK} = 5V$ , MCLK = 16.384MHz,  $T_A = +25$ °C, 1kHz signal

Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units
Auxiliary Analog Inputs (AU	XIN)				10%	7
Full scale input signal <sup>1</sup>		Gain = 0dB		1.0 0	-0	Vrms dBV
AUX Programmable gain			0		9	dB
AUX programmable gain step size		Guaranteed Monotonic		3		dB
Input resistance		Aux direct-to-out path, only Input gain = +9.0dB Input gain = +6.0dB Input gain = +3.0dB Input gain = 0dB		21 27 33 40		kΩ kΩ kΩ kΩ
Aux-in Gain Accuracy	A <sub>AUX(GA)</sub>		-0.5dB		+0.5dB	dB

Conditions: VCCD = 3.3V, VCCA = VCCSPK = 3.3V, MCLK = 16.384MHz, TA = +25°C, 1kHz signal

Conditions. $V_{CCD} = 3.3V$ , $V_{CCA} = V$	CCSPK = 3.3 V	, IVIOLIX - 10.304IVII IZ, 1A = +2	ZO O, IKIIZ	Signal		
Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units
Auxiliary Analog Inputs (AUX	XIN)					
Full scale input signal 1		Gain = 0dB		1.0		Vrms
107 F. S.				0		dBV
AUX Programmable gain			0		9	dB
AUX programmable gain step size		Guaranteed Monotonic		3		dB
Input resistance	Raux_in	Aux direct-to-out path,				
	S	only		21		kΩ
	2)6	Input gain = +9.0dB		27		kΩ
		Input gain = +6.0dB				

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Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units
		Input gain = +3.0dB		33		kΩ
		Input gain = 0dB		40		kΩ
Aux-in Gain Accuracy	A <sub>AUX(GA)</sub>	9/2 3/11	-0.5dB		+0.5dB	dB



#### 6.3.3 Outputs

#### **Aux-out**

Conditions:  $V_{CCD} = 3.3V$ ,  $V_{CCA} = V_{CCSPK} = 5V$ , MCLK = 16.384MHz,  $T_A = +25$ °C, 1kHz signal

Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units	
Digital to Analog Converter (DAC) driving AUXOUT with 5kΩ / 100pF load							
Full-scale output		Gain paths all at 0dB gain	XX	V <sub>CCA</sub> / 3.3		$V_{rms}$	
Signal-to-noise ratio	SNR	A-weighted	33/4	85		dB	
Total harmonic distortion <sup>2</sup>	THD+N	$R_L = 5k\Omega$ ; full-scale signal A-weighted		-80		dB	

Conditions:  $V_{CCD} = 3.3V$ ,  $V_{CCA} = V_{CCSPK} = 3.3V$ , MCLK = 16.384MHz,  $T_A = +25$ °C, 1kHz signal

Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units		
Digital to Analog Converter (DAC) driving AUXOUT with 5kΩ / 100pF load								
Full-scale output		Gain paths all at 0dB gain		V <sub>CCA</sub> / 3.3		$V_{rms}$		
Signal-to-noise ratio	SNR	A-weighted		80	- (	dB		
Total harmonic distortion <sup>2</sup>	THD+N	$R_L = 5k\Omega$ ; full-scale signal A-weighted		-77		dB		



#### **PWM OUTPUT**

Conditions:  $V_{CCD} = 3.3V$ ,  $V_{CCA} = V_{CCSPK} = 5V$ , MCLK = 16.384MHz,  $T_A = +25$ °C, 1kHz signal

Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units		
Speaker PWM Output (SPK_	Speaker PWM Output (SPK_PLUS / SPK_MINUS with 8Ω bridge-tied-load)							
Signal-to-noise ratio <sup>3</sup>	SNR	A-weighted + Class D Filter	1/4	65		dB		
Total harmonic distortion <sup>2</sup>	THD	P <sub>o</sub> = 1W, A-weighted + Class D Filter	XX	-40		dB		
Efficiency	E <sub>PWM</sub>	8Ω bridge-tied-load Pout > 0.2W	3377	85		%		

Conditions:  $V_{CCD} = 3.3V$ ,  $V_{CCA} = V_{CCSPK} = 3.3V$ , MCLK = 16.384MHz,  $T_A = +25$ °C, 1kHz signal

Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units
Speaker PWM Output (SPK_	PLUS / SPK	C_MINUS with 8Ω bridge-	tied-load)	9	76	2
Signal-to-noise ratio <sup>3</sup>	SNR	A-weighted + Class D Filter		65	20	dB
Total harmonic distortion <sup>2</sup>	THD	A-weighted + Class D Filter		-40	Chi.	dB
Efficiency	E <sub>PWM</sub>	$8\Omega$ bridge-tied-load Pout > 0.2W		80		%

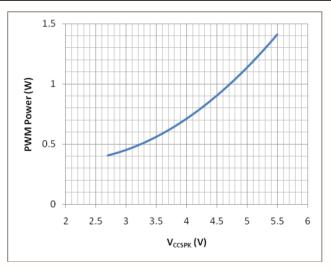


Figure 6-2 PWM Power vs. V<sub>CCSPK</sub>



#### **CLASS-AB BTL OUTPUT**

Conditions:  $V_{CCD} = 3.3V$ ,  $V_{CCA} = V_{CCSPK} = 5V$ , MCLK = 16.384MHz,  $T_A = +25$ °C, 1kHz signal

Parameter	Symbol	Comments/Conditions	Min	Тур	Max	Units		
Speaker CLASS-AB BTL Out	Speaker CLASS-AB BTL Output (SPK_PLUS / SPK_MINUS with 8Ω bridge-tied-load)							
Full scale output		Gain paths all at 0dB gain	All.	V <sub>CCA</sub> / 3.3	1	$V_{rms}$		
Signal-to-noise ratio	SNR	A-weighted	X	90		dB		
Total harmonic distortion <sup>2</sup>	THD	P <sub>o</sub> = 1W, A-weighted		-60		dB		
Efficiency	E <sub>AB</sub>	8Ω bridge-tied-load Pout > 0.7W	3%	50		%		

Conditions:  $V_{CCD} = 3.3V$ ,  $V_{CCA} = V_{CCSPK} = 3.3V$ , MCLK = 16.384MHz,  $T_A = +25$ °C, 1kHz signal

**= ' **:		, , , , , , , , , , , , , , , , , , , ,					
Parameter	Symbol	Comments/Conditions	Min Typ	Max	Units		
Speaker CLASS-AB BTL Output (SPK_PLUS / SPK_MINUS with 8Ω bridge-tied-load)							
Full scale output		Gain paths all at 0dB gain	V <sub>CCA</sub> / 3.3		$V_{rms}$		
Signal-to-noise ratio	SNR	A-weighted	84	18	dB		
Total harmonic distortion <sup>2</sup>	THD	A-weighted	-60	110	dB		
Efficiency	E <sub>AB</sub>	8Ω bridge-tied-load Pout > 0.4W	50		%		

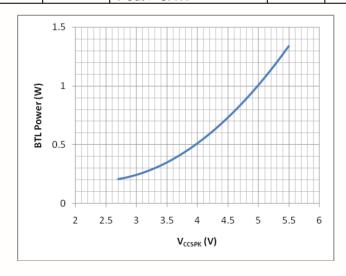


Figure 6-3 Class-AB BTL Power vs. V<sub>CCSPK</sub>

#### **Notes**

- 1. Full Scale is relative to the magnitude of VCCA and can be calculated as FS = VCCA/3.3.
- 2. Distortion is measured in the standard way as the combined quantity of distortion products plus noise. The signal level for distortion measurements is at 3dB below full scale, unless otherwise noted.
- 3. SNR measured with a -100dbFS signal at input.

### 6.3.4 SPI Timing

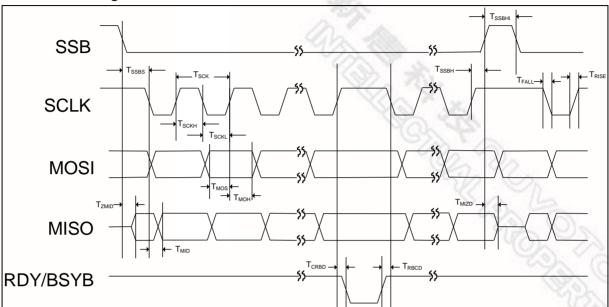


Figure 6-4 SPI Timing

SYMBOL	DESCRIPTION	MIN	TYP	MAX	UNIT
T <sub>SCK</sub>	SCLK Cycle Time	60			ns
T <sub>SCKH</sub>	SCLK High Pulse Width	25			ns
T <sub>SCKL</sub>	SCLK Low Pulse Width	25			ns
T <sub>RISE</sub>	Rise Time for All Digital Signals			10	ns
T <sub>FALL</sub>	Fall Time for All Digital Signals			10	ns
T <sub>SSBS</sub>	SSB Falling Edge to 1 <sup>st</sup> SCLK Falling Edge Setup Time	30			ns
T <sub>SSBH</sub>	Last SCLK Rising Edge to SSB Rising Edge Hold Time	30ns		50us	
T <sub>SSBHI</sub>	SSB High Time between SSB Lows	20			ns
T <sub>MOS</sub>	MOSI to SCLK Rising Edge Setup Time	15			ns
T <sub>MOH</sub>	SCLK Rising Edge to MOSI Hold Time	15			ns
$T_{ZMID}$	Delay Time from SSB Falling Edge to MISO Active			12	ns
T <sub>MIZD</sub>	Delay Time from SSB Rising Edge to MISO Tri-state			12	ns



SYMBOL	DESCRIPTION		TYP	MAX	UNIT
T <sub>MID</sub>	Delay Time from SCLK Falling Edge to MISO			12	ns
T <sub>CRBD</sub>	Delay Time from SCLK Rising Edge to RDY/BSYB Falling Edge	-		12	ns
T <sub>RBCD</sub>	Delay Time from RDY/BSYB Rising Edge to SCLK Falling Edge	0			ns

### 6.3.5 I<sup>2</sup>S Timing

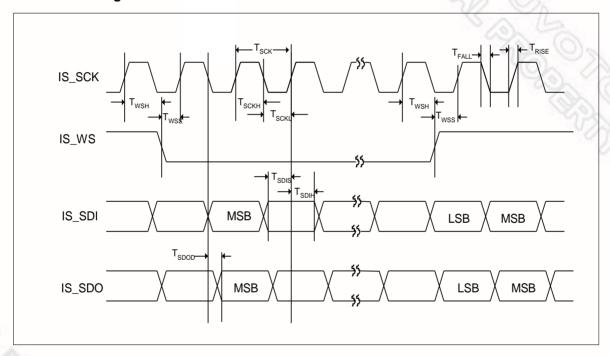


Figure 6-5 I<sup>2</sup>S Timing

SYMBOL	DESCRIPTION		TYP	MAX	UNIT
T <sub>SCK</sub>	IS_SCK Cycle Time	60			ns
T <sub>SCKH</sub>	IS_SCK High Pulse Width	25			ns
T <sub>SCKL</sub>	IS_SCK Low Pulse Width	25			ns
T <sub>RISE</sub>	Rise Time for All Digital Signals			10	ns
T <sub>FALL</sub>	Fall Time for All Digital Signals			10	ns



SYMBOL	DESCRIPTION	MIN	TYP	MAX	UNIT
T <sub>WSS</sub>	WS to IS_SCK Rising Edge Setup Time	20			ns
T <sub>WSH</sub>	IS_SCK Rising Edge to IS_WS Hold Time	20			ns
T <sub>SDIS</sub>	IS_SDI to IS_SCK Rising Edge Setup Time	15			ns
T <sub>SDIH</sub>	IS_SCK Rising Edge to IS_SDI Hold Time	15			ns
T <sub>SDOD</sub>	Delay Time from IS_SCLK Falling Edge to IS_SDO	23	199	12	ns



### 7 APPLICATION DIAGRAM

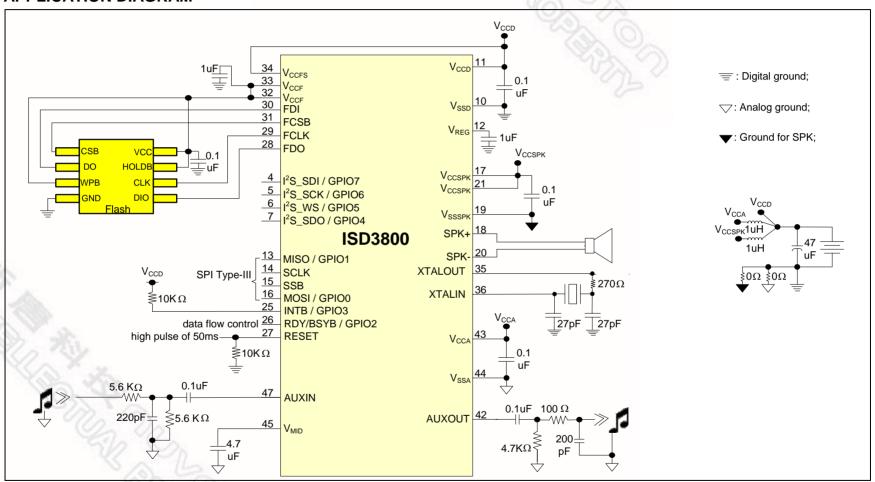


Figure 7-1 ISD3800 Application Diagram – V<sub>CCF</sub> is regulated internally from V<sub>CCFS</sub>

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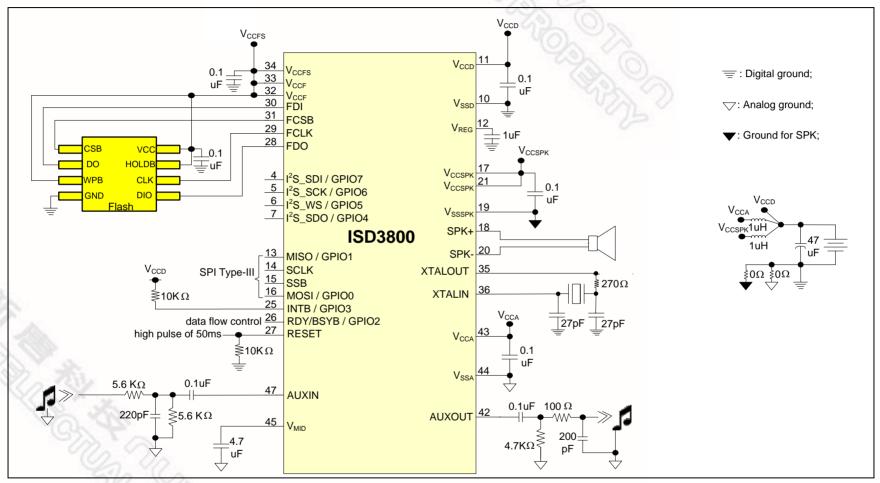


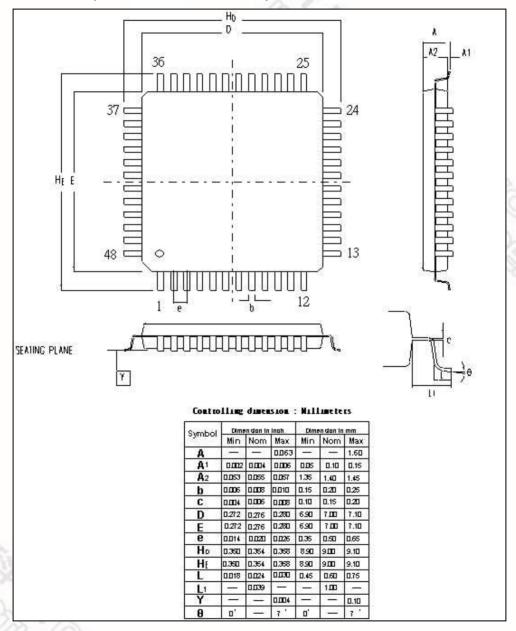
Figure 7-2 ISD3800 Application Diagram –  $V_{\text{CCF}}$  is tied to  $V_{\text{CCFS}}$ 

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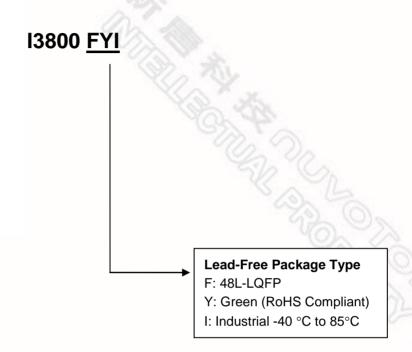
#### **8 PACKAGE SPECIFICATION**

#### 8.1 48 LEAD LQFP(7x7x1.4MM FOOTPRINT 2.0MM)





### 9 ORDERING INFORMATION





### 10 REVISION HISTORY

Version	Date	Description
0.23	Aug 3, 2009	Initially released as the Preliminary Datasheet.
0.26	Aug 17, 2009	Update application diagram.
0.27	Sep 28, 2009	Update the list of supported Flash Memory.
0.29	Nov 18, 2009	Update:      Block Diagram.     Electrical Characteristics.
0.35	Feb 8, 2010	Update block diagram.
0.40	July 1, 2010	Update crystal configuration.
0.50	Aug 12, 2010	Update PWM spec.
0.60	Sep 22, 2010	Update ordering information.
1.0	Aug 23, 2013	Add internal oscillator characteristics.



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